Preferred Device

JFET - General Purpose Transistor

N-Channel

Features

• Pb–Free Package is Available

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	25	Vdc
Drain-Gate Voltage	V _{DG}	25	Vdc
Reverse Gate-Source Voltage	V _{GS(r)}	-25	Vdc
Gate Current	I _G	10	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) $(T_A = 25^{\circ}C)$ Derate above 25°C	PD	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	556	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

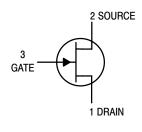
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.



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SOT-23 (TO-236) **CASE 318** STYLE 10

MARKING DIAGRAM



= Specific Device Code Μ

= Date Code*

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= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBF5457LT1	SOT-23	3000/Tape & Reel
MMBF5457LT1G	SOT-23 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

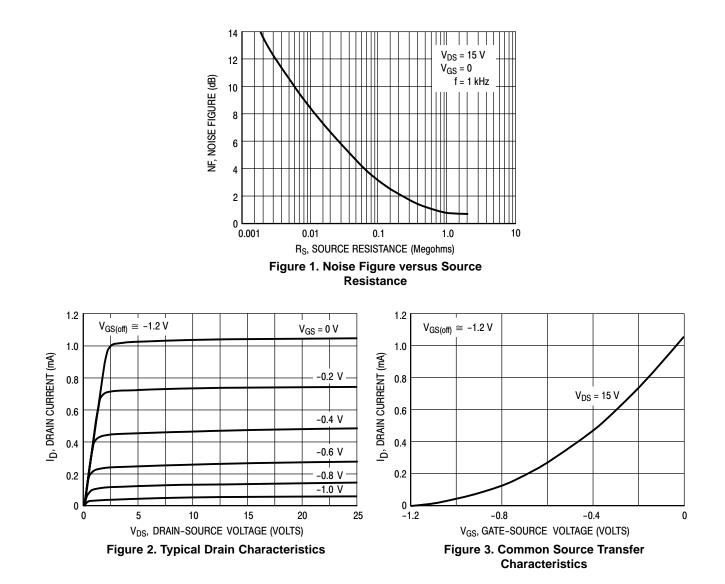
Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

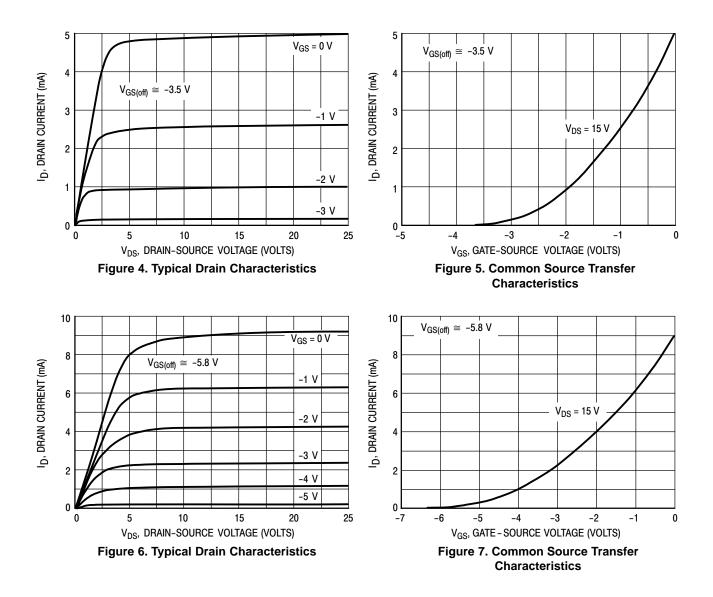
Symbol	Min	Тур	Max	Unit
V _{(BR)GSS}	-25	-	-	Vdc
I _{GSS}			-1.0 -200	nAdc
V _{GS(off)}	-0.5	-	-6.0	Vdc
V _{GS}	-	-2.5	-	Vdc
IDSS	1.0	-	5.0	mAdc
Y _{fs}	1000	_	5000	μmhos
y _{os}	-	10	50	μmhos
C _{iss}	-	4.5	7.0	pF
C _{rss}	-	1.5	3.0	pF
	V(BR)GSS V(BR)GSS IGSS VGS(off) VGS IDSS IVfsl IVosl Ciss	$\begin{array}{c c c c c c c c c } V_{(BR)GSS} & -25 \\ & I_{GSS} & - \\ & & - \\ & V_{GS(off)} & -0.5 \\ & V_{GS} & - \\ \hline & V_{GS} & - \\ & & I_{DSS} & 1.0 \\ \hline & & I_{DSS} & 1.0 \\ & & & I_{SS} & - \\ \hline & & & & I_{SS} & - \\ \hline & & & & & I_{SS} & - \\ \hline & & & & & & I_{SS} & - \\ \hline & & & & & & I_{SS} & - \\ \hline & & & & & & & I_{SS} & - \\ \hline & & & & & & & I_{SS} & - \\ \hline & & & & & & & I_{SS} & - \\ \hline & & & & & & & I_{SS} & - \\ \hline & & & & & & & I_{SS} & - \\ \hline & & & & & & & I_{SS} & - \\ \hline \end{array}$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	V(BR)GSS -25 - - IGSS - - - - VGS(off) -0.5 - -6.0 VGS - -2.5 - IDSS 1.0 - 5.0 IDSS 1.00 - 5000 IVGS - 10 50 IVGS - 4.5 7.0

2. Pulse Test: Pulse Width \leq 630 ms, Duty Cycle \leq 10%.

TYPICAL CHARACTERISTICS



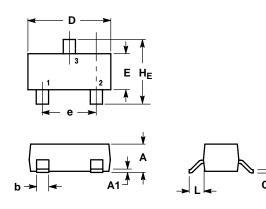
TYPICAL CHARACTERISTICS



Note: Graphical data is presented for dc conditions. Tabular data is given for pulsed conditions (Pulse Width = 630 ms, Duty Cycle = 10%). Under dc conditions, self heating in higher I_{DSS} units reduces I_{DSS}.

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AL**



NOTES:

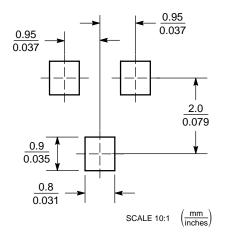
- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL. 4. 318–01 THRU –07 AND –09 OBSOLETE, NEW STANDARD 318–08.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
c	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
Е	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.081
Г	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 10: PIN 1. DRAIN

- 2. SOURCE 3. GATE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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